

# Ultrafast Rectifier, 1 A FRED Pt®

## eSMP® Series



Cathode  Anode

**SMF (DO-219AB)**

## FEATURES

- Ultrafast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- For PCF CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Wave and reflow solderable
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## DESIGN SUPPORT TOOLS

[click logo to get started](#)

**3D**  
Models  
Available

## PRIMARY CHARACTERISTICS

$I_{F(AV)}$	1 A
$V_R$	600 V
$V_F$ at $I_F$	0.83 V
$t_{rr}$	55 ns
$T_J$ max.	175 °C
Package	SMF (DO-219AB)
Circuit configuration	Single

## DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 158\text{ °C}^{(1)}$	1	A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$ , 6 ms square pulse	30	
Operating junction and storage temperature range	$T_J, T_{Stg}$		-55 to +175	°C

### Note

<sup>(1)</sup> Device on PCB with 8 mm x 16 mm soldering lands

## ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	$V_F$	$I_F = 1\text{ A}$	-	1.0	1.2	
		$I_F = 1\text{ A}$ , $T_J = 150\text{ °C}$	-	0.83	1	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	3	$\mu\text{A}$
		$T_J = 150\text{ °C}$ , $V_R = V_R$ rated	-	20	100	
Junction capacitance	$C_T$	$V_R = 600\text{ V}$	-	5	-	pF

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1\text{ A}$ , $dI_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	42	-	ns
		$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$	-	-	55	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	32	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	47	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	4.8	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	6.8	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	77	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	160	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^{\circ}\text{C}$
Thermal resistance, junction to case	$R_{thJC}$	Device mounted on PCB with 8 mm x 16 mm soldering lands	-	-	15	$^{\circ}\text{C}/\text{W}$
Thermal resistance, junction to ambient	$R_{thJA}$	Device mounted on PCB with 2 mm x 3.5 mm soldering lands	-	-	130	$^{\circ}\text{C}/\text{W}$
Approximate weight			0.015			g
			0.0005			oz.
Marking device		Case style SMF (DO-219AB)	MNU			

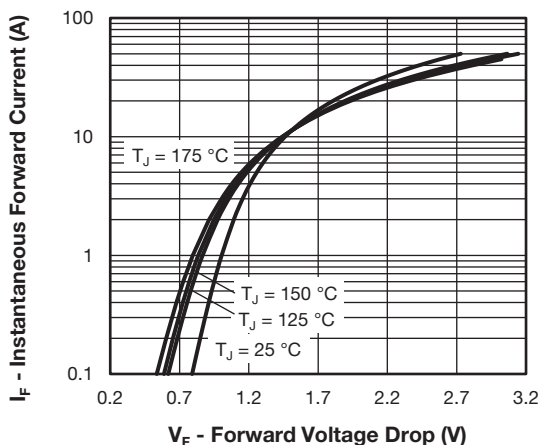


Fig. 1 - Typical Forward Voltage Drop Characteristics

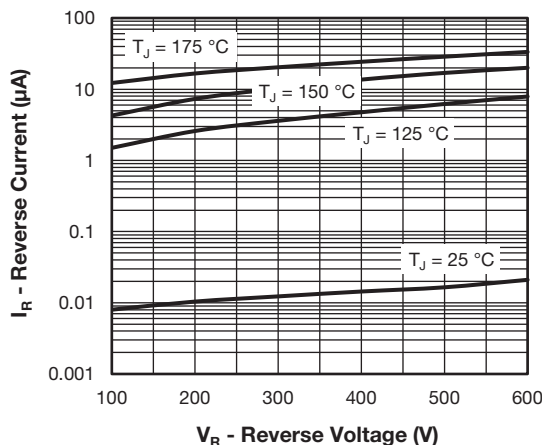


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

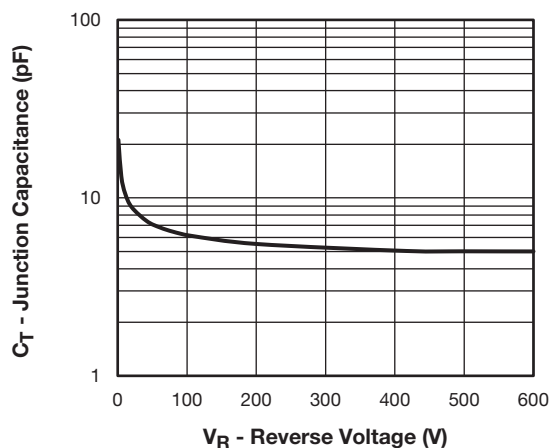


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

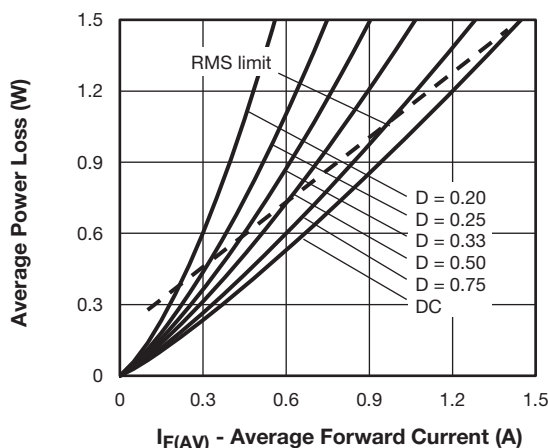


Fig. 5 - Forward Power Loss Characteristics

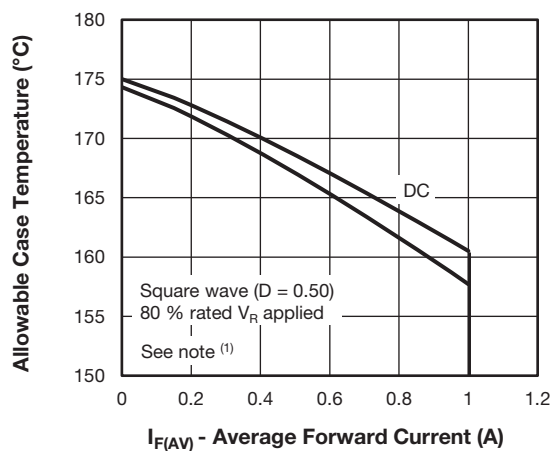
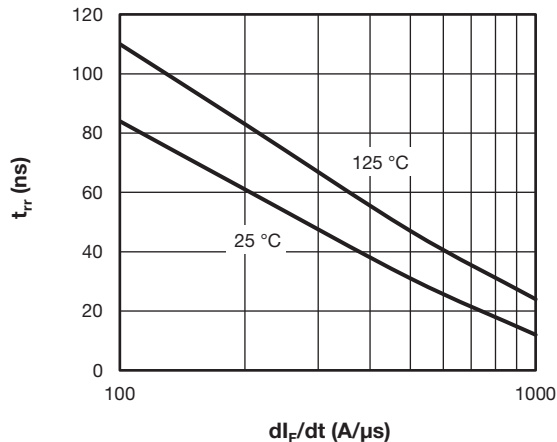
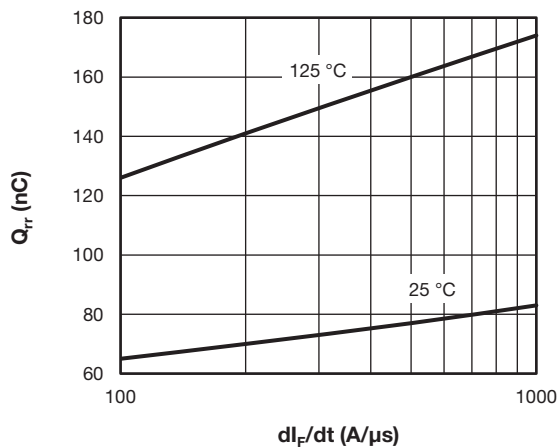


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current


Fig. 6 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$ 
**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

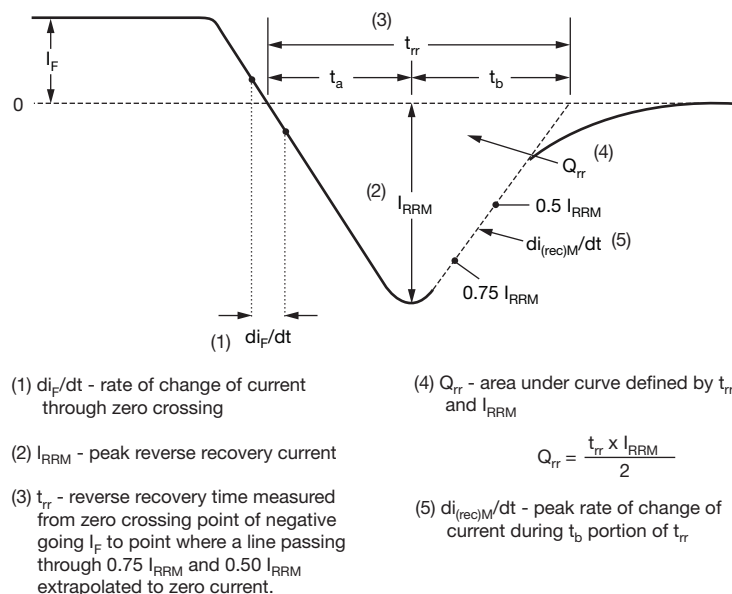


Fig. 8 - Reverse Recovery Waveform and Definitions

## ORDERING INFORMATION TABLE

Device code	VS-	1	E	F	U	06	H	M3
	1	2	3	4	5	6	7	8

- 1** - Vishay Semiconductors product
- 2** - Current rating (1 = 1 A)
- 3** - Circuit configuration:  
E = single diode
- 4** - F = SMF package
- 5** - Process type,  
U = ultrafast recovery
- 6** - Voltage code (06 = 600 V)
- 7** - H = AEC-Q101 qualified
- 8** - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

## ORDERING INFORMATION (Example)

PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-1EFU06HM3/I	10 000	10 000	13" diameter plastic tape and reel

## LINKS TO RELATED DOCUMENTS

Dimensions	<a href="http://www.vishay.com/doc?95572">www.vishay.com/doc?95572</a>
Part marking information	<a href="http://www.vishay.com/doc?95618">www.vishay.com/doc?95618</a>
Packaging information	<a href="http://www.vishay.com/doc?95577">www.vishay.com/doc?95577</a>
SPIICE model	<a href="http://www.vishay.com/doc?95639">www.vishay.com/doc?95639</a>



## SMF (DO-219AB)

**DIMENSIONS** in millimeters (inches)



Foot print recommendation:



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17247



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